Application No. 10/626,675

Attorney Docket No.: 030901

Amendment Filed: June 28, 2007

AMENDMENTS TO THE CLAIMS

The listing of claims below replaces all prior versions of claims in the application.

1. (Currently Amended) A susceptor of an approximately round disk shape, having a

concave wafer pocket on a front surface thereof for accommodating a wafer, comprising:

a gas supply channel having a first opening passing through from a rear surface of the

susceptor to the wafer pocket, a first notch provided in a side surface of the susceptor, and a first

groove formed on the rear surface of the susceptor and extended from a periphery of the rear

surface of the susceptor the first notch to the first opening and having a shape adapted to supply a

gas into the wafer pocket as the susceptor rotates in a predetermined direction; and

a gas discharge channel having a second opening passing through from the wafer pocket

to the rear surface of the susceptor, a second notch provided in the side surface of the susceptor,

and having a second groove formed on the rear surface of the susceptor and extended from the

periphery-of the rear surface of the susceptor the second notch to the second opening and having

a shape adapted to discharge the gas present in the wafer pocket as the susceptor rotates in the

predetermined direction.

2. (Cancelled).

3. (Withdrawn) An epitaxial wafer production apparatus comprising:

a chamber having a gas supply vent and a gas discharge vent;

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surface;

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a susceptor of an approximately round disk shape, which is disposed inside the chamber and comprises a concave wafer pocket on the front surface thereof for accommodating a wafer, a gas supply channel passing through from a side surface or a rear surface to the wafer pocket, and a gas discharge channel passing through from the wafer pocket to the side surface or the rear

support means for supporting the susceptor; and

heating means for heating the susceptor and the wafer inside the chamber.

4. (Withdrawn) The epitaxial wafer production apparatus according to claim 3, comprising a gas supply vent for supplying a carrier gas containing a raw material gas only above the susceptor located inside the chamber.

5. (Withdrawn) An epitaxial wafer production apparatus comprising:

a chamber;

a susceptor disposed inside the chamber and comprising a concave wafer pocket on a front surface thereof for accommodating a wafer;

support means for supporting the susceptor; and

heating means for heating the susceptor and the wafer inside the chamber, wherein the apparatus further comprises:

a gas supply vent for supplying a carrier gas containing a raw material gas to above the susceptor located inside the chamber; and

the susceptor located inside the chamber.

a heavy gas supply vent for supplying a gas which is heavier than the carrier gas to under

6. (Withdrawn) A method for producing an epitaxial wafer, comprising the steps of:

placing a wafer into a concave wafer pocket formed on a front surface of a susceptor

disposed inside a chamber;

supplying a gas from under the susceptor into the wafer pocket;

discharging a gas present inside the wafer pocket from under the susceptor; and

heating the susceptor and the wafer inside the chamber.

7. (Withdrawn) A method for producing an epitaxial wafer, comprising the steps of:

placing a wafer onto a susceptor disposed inside a chamber;

supplying a carrier gas containing a raw material gas to above the susceptor inside the

chamber and supplying a gas heavier than the carrier gas to under the susceptor; and

heating the susceptor and the wafer inside the chamber.

8-9. (Cancelled)

10. (Previously Presented) The susceptor according to claim 1, wherein the first groove

is formed so as to curve along the rear surface of the susceptor from the periphery of the rear

surface of the susceptor to the first opening, and the second groove is formed so as to curve

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along the rear surface of the susceptor from the periphery of the rear surface of the susceptor to

the second opening.

11. (Currently Amended) A susceptor of an approximately round disk shape, having a

concave wafer pocket on a front surface thereof for accommodating a wafer, comprising:

a gas supply channel having an opening passing through from a rear surface of the

susceptor to the wafer pocket, a notch provided in a side surface of the susceptor, and a groove

formed on the rear surface of the susceptor and extended from a periphery of the rear surface of

the susceptor the notch to the opening and having a shape adapted to supply a gas into the wafer

pocket as the susceptor rotates in a predetermined direction; and

a gas discharge channel passing through from the wafer pocket to the rear surface of the

susceptor and having a shape adapted to discharge the gas present in the wafer pocket as the

susceptor rotates, the gas discharge channel being positioned at a center side of the susceptor

relative to the gas supply channel.

12. (Previously Presented) The susceptor according to claim 11, wherein the groove is

formed so as to curve along the rear surface of the susceptor from the periphery of the rear

surface of the susceptor to the opening, and the gas discharge channel is formed so as to curve

from the rear surface of the susceptor to a front of the susceptor.

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